# 28.3% Ultra Triple Junction (UTJ) Solar Cells



#### **Features**

- Small and large cell sizes offered for optimum packing factor and cost competitiveness
- All sizes qualified for LEO and GEO missions
- Discrete Si bypass diode protection
- Performance for cells <32 cm<sup>2</sup> is 28.3% efficiency (min. average @ max power, 28°C, AM0)
- Performance for cells >50 cm<sup>2</sup> is 27.7% efficiency (min. average @ max power, 28°C, AM0)
- Available as CIC assembly (Cell-Interconnect-Coverglass with diode) for ease of integration or delivered on completed solar panels (see Panel Data Sheet)



Cells shown with interconnects, coverglass, and bypass diode

Key Qualification Results				
Low Earth Orbit (LEO)	66,060 cycles			
Geostationary Orbit (GEO)	15,550 cycles			
Multiple Interplanetary Missions: Mars, Jupiter, Asteroid				
ESD Survivability Tested to ISO Standard				

### **Product Description**

Substrate	Germanium	
Solar Cell Structure	GalnP <sub>2</sub> /GaAs/Ge	
Method	Metal Organic Vapor Phase Epitaxy	
Device Design	Monolithic, two terminal triple junction. n/p GaInP <sub>2</sub> , GaAs, and Ge solar cells interconnected with two tunnel junctions	
Standard Sizes	26.62cm² and 59.65cm² are most cost effective and common standard sizes; other sizes available	
Assembly Method	Welded	
CIC Assembly	Coverglass thickness range from 3 mils to 30 mils with various coatings. Interconnects available with either out-of-plane or in-plane stress relief	

© 2010 Spectrolab, Inc All Rights Reserved

## Heritage

- More than 2.6 million multi-junction cells delivered
- More than 820 kW of multi-junction arrays on orbit
- Large area cell (59.65cm²) delivered on solar panels for 25 satellites (LEO constellation)
- 1 MW annual capacity cells and panels

## Intellectual Property

This product is protected by Spectrolab's portfolio of patents including the following:

- 6,150,603
- 7,119,271
- 6,255,580
- 7,126,052
- 6,380,601

Specifications Subject to Change Without Notice





# 28.3% Ultra Triple Junction (UTJ) Solar Cells

#### Typical Electrical Parameters

(AMO (135.3 mW/cm²) 28°C, Bare Cell)

Parameters	< 32 cm <sup>2</sup>	> 50 cm²
Jsc	17.05 mA/cm <sup>2</sup>	17.05 mA/cm <sup>2</sup>
Jmp	16.30 mA/cm <sup>2</sup>	16.30 mA/cm <sup>2</sup>
Jload min avg	16.40 mA/cm <sup>2</sup>	16.40 mA/cm <sup>2</sup>
Voc	2.660 V	2.660 V
Vmp	2.350 V	2.300 V
Vload	2.310 V	2.270 V
Cff	0.85	0.83
Effload	28.0%	27.5%
Effmp	28.3%	27.6%

### Radiation Degradation

(Fluence 1MeV Electrons/cm²)

<u> </u>			
Parameters	1x10 <sup>14</sup>	5x10 <sup>14</sup>	1x10 <sup>15</sup>
Imp/Imp <sub>0</sub>	0.99	0.98	0.96
Vmp/Vmp <sub>0</sub>	0.94	0.91	0.89
Pmp/Pmp <sub>0</sub>	0.93	0.89	0.86

## **Thermal Properties**

Solar Absorptance= 0.92 (5 mil CMG/AR, 0.90 for bare cells)

Emittance (Normal) = 0.85 (Ceria Doped Microsheet)

## Weight

84 mg/ cm² (Bare) @ 140 µm (5.5 mil) Ge wafer thickness

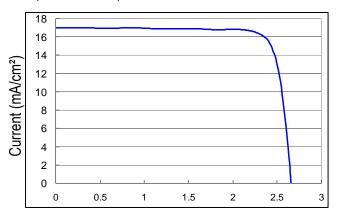
## **Temperature Coefficients** (15°C - 80°C)

(Fluence 1MeV Electrons/cm²)

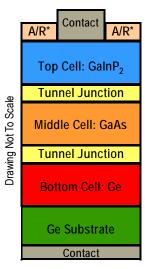
	•		
Parameters	BOL	5x10 <sup>14</sup>	1x10 <sup>15</sup>
Jmp (µA/cm²/°C)	1.2	5.3	6.9
Jsc (µA/cm²/°C)	5.3	6.5	6.9
Vmp (mV/°C)	-6.5	-6.7	-6.8
Voc (mV/°C)	-5.9	-6.3	-6.5

### Typical IV Characteristic

AM0 (135.3 mW/cm<sup>2</sup>) 28°C, Bare Cell



Voltage (V)



\*A/R: Anti-Reflective Coating

The information contained on this sheet is for reference only. Specifications subject to change without notice.

Revised 10/5/2010

© 2010 Spectrolab, Inc All Rights Reserved



ENVIRONMENTAL MANAGEMENT SYSTEM
CERTIFIED BY DNV

150 14001

